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由对称性

$$E_x = E_y = 0$$

对于 E_z

$$\begin{aligned}
E_z &= \frac{\sigma_e}{4\pi\epsilon_0} \int_0^{2\pi} d\theta \int_{\frac{\pi}{2}}^{\pi} d\phi \left[\sin\phi \frac{\cos\phi}{R^3} \right] \\
&= \frac{\sigma_e}{2\epsilon_0} \int_{\frac{\pi}{2}}^{\pi} d\phi \left[\sin\phi \frac{\cos\phi}{R^3} \right] \\
&= \frac{\sigma_e}{4\epsilon_0} \int_{\frac{\pi}{2}}^{\pi} d\phi \left[\sin 2\phi \frac{1}{R^3} \right] \\
&= \frac{\sigma_e}{4\epsilon_0 R^3}
\end{aligned}$$

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我们记

$$\begin{aligned}
R &= 0.5\text{m} \quad l = 2\text{cm} \quad q = 3.12 \times 10^{-9}\text{C} \\
\sigma &= q/(2\pi R - l) \sim q/2\pi R
\end{aligned}$$

我们假定圆环无缺，则又对称性，中心电场强度为 0

而缺少部分若存在，由对称性对圆心的电场强度近似为

$$\begin{aligned}
E_y &= \frac{\sigma}{4\pi R} \int_{-\frac{l}{2\pi R}}^{\frac{l}{2\pi R}} R d\theta \frac{\cos\theta}{R^2} \\
&= \frac{\sigma}{4\pi R^2} (\sin\theta) \Big|_{-\frac{l}{2\pi R}}^{\frac{l}{2\pi R}} \\
&\approx \frac{\sigma l}{4\pi^2 R^3} \\
&\approx \frac{ql}{8\pi^3 R^4} \\
&\approx 4.02499 \times 10^{-12} \text{N/C}
\end{aligned}$$

方向指向缺口对面，而缺失则导致剩余部分有一个强度为 E_y 指向缺口处的场强

1-13

由对称性 $E_x = E_y = 0$

对于 E_z

$$\begin{aligned}
E_z &= \frac{Q/(2\pi RL)}{4\pi\epsilon_0} \int_0^L 2\pi R dz \frac{L+a-z}{\left(\sqrt{(L+a-z)^2 + R^2}\right)^3} \\
&= -\frac{Q}{8\epsilon_0\pi L} \int_0^L \frac{d(L+a-z)^2}{\left(\sqrt{(L+a-z)^2 + R^2}\right)^3} \\
&= \frac{Q}{4\epsilon_0\pi L} \int_0^L d \frac{1}{\sqrt{(L+a-z)^2 + R^2}} \\
&= \frac{Q}{4\epsilon_0\pi L} \left(\frac{1}{\sqrt{a^2 + R^2}} - \frac{1}{\sqrt{(L+a)^2 + R^2}} \right)
\end{aligned}$$

1-14

由对称性 $E_y = E_z = 0$

对于 E_x

$$\begin{aligned}
E_x &= \sigma_e \int_0^\pi R d\theta \left(-\frac{\sin \theta}{2\pi R \epsilon_0} \right) \\
&= \frac{\sigma_e}{\pi R \epsilon_0}
\end{aligned}$$

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考虑对称性, $E_y = E_z = 0$

对于 E_x 有

$$\begin{aligned}
E_x &= \frac{\sigma_e}{4\pi\epsilon_0} \left(\int_0^\pi a d\theta \left(-\frac{\sin \theta}{a^2} \right) + 2 \int_0^{\frac{\pi}{2}} \frac{a}{\cos^2 \theta} d\theta \left(-\frac{\sin \theta}{(a/\cos \theta)^2} \right) \right) \\
&= \frac{\sigma_e}{4\pi\epsilon_0} \left(\int_0^\pi d\theta \left(-\frac{\sin \theta}{a} \right) + 2 \int_0^{\frac{\pi}{2}} d\theta \left(\frac{\sin \theta}{a} \right) \right) \\
&= \frac{\sigma_e}{4\pi\epsilon_0} \left(\int_0^\pi d\theta \left(-\frac{\sin \theta}{a} \right) + \int_0^\pi d\theta \left(\frac{\sin \theta}{a} \right) \right) \\
&= 0
\end{aligned}$$

1-18

由高斯定理, 有

$$\nabla \cdot \vec{E} = 0 \Rightarrow \rho = 0 \Rightarrow q = 0$$

1-20

由高斯定理, 以及氢原子的球对称性, 距原子核 r 处的电场方向为原子核指向此处, 大小为

$$\begin{aligned}
E &= \frac{1}{4\pi r^2 \varepsilon_0} \left(q + \int_0^r dR \int_0^{2\pi} d\theta \int_0^\pi d\phi R^2 \sin \phi (\rho_e(r)) \right) \\
&= \frac{1}{4\pi r^2 \varepsilon_0} \left(q + \int_0^r dR \int_0^{2\pi} d\theta \int_0^\pi d\phi R^2 \sin \phi \left(-\frac{q}{\pi a_0^3} e^{-2R/a_0} \right) \right) \\
&= \frac{1}{4\pi r^2 \varepsilon_0} \left(q + 4 \int_0^r dR R^2 \left(-\frac{q}{a_0^3} e^{-2R/a_0} \right) \right) \\
&= \frac{1}{4\pi r^2 \varepsilon_0} \left(q + \frac{2r^2 q}{a_0^2} e^{-2r/a_0} - 4 \int_0^r dR \frac{qR}{a_0^2} e^{-2R/a_0} \right) \\
&= \frac{1}{4\pi r^2 \varepsilon_0} \left(q + \frac{2r^2 q}{a_0^2} e^{-2r/a_0} + 2r \frac{q}{a_0} e^{-2r/a_0} - 2 \int_0^r dR \frac{q}{a_0} e^{-2R/a_0} \right) \\
&= \frac{q}{4\pi r^2 \varepsilon_0} \left(\frac{2r^2}{a_0^2} e^{-2r/a_0} + \frac{2r}{a_0} e^{-2r/a_0} + e^{-2r/a_0} \right)
\end{aligned}$$

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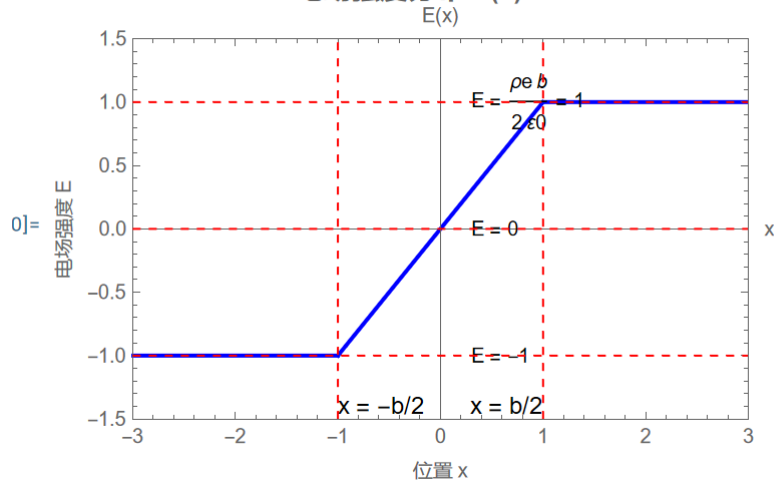
由高斯定理和对称性，有

$$\begin{aligned}
E &= \frac{1}{2\pi r \varepsilon_0} \int_0^r dR \int_0^{2\pi} d\theta R (\rho_e(R)) \\
&= \frac{1}{2\pi r \varepsilon_0} \int_0^r dR \int_0^{2\pi} d\theta \frac{R \rho_0}{\left[1 + (R/a)^2\right]^2} \\
&= \frac{1}{r \varepsilon_0} \int_0^r dR \frac{R \rho_0}{\left[1 + (R/a)^2\right]^2} \\
&= \frac{a^2 \rho_0}{2r \varepsilon_0} \left(1 - \frac{1}{1 + r^2/a^2} \right)
\end{aligned}$$

1-27

$$\begin{aligned}
|x| \geq \frac{b}{2} : E &= \frac{\rho_e b}{2\varepsilon_0} \cdot \frac{x}{|x|} \\
|x| < \frac{b}{2} : E &= \frac{\rho_e x}{\varepsilon_0}
\end{aligned}$$

电场强度分布 $E(x)$ vs x



1-28

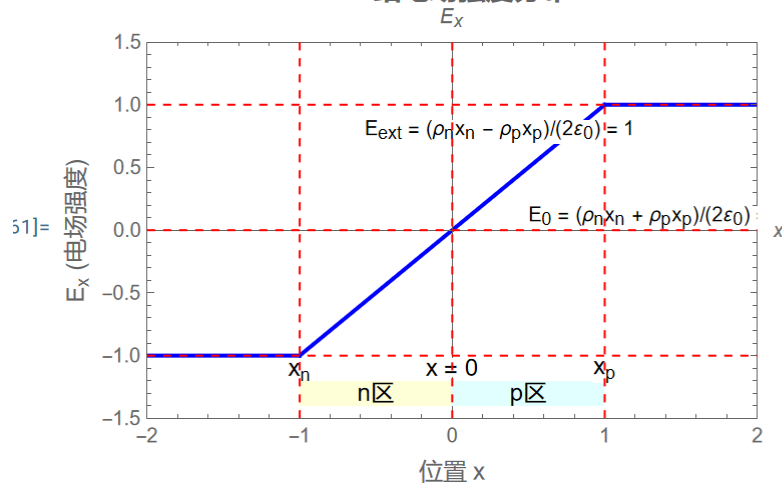
由 1-27 可知

$$x \geq x_p \text{ or } x \leq x_n : E = \left(\frac{\rho_n x_n}{2\epsilon_0} - \frac{\rho_p x_p}{2\epsilon_0} \right) \cdot \frac{x}{|x|}$$

$$-x_n < x \leq 0 : E = \frac{\rho_n}{\epsilon_0} \left(x + \frac{x_n}{2} \right) + \frac{\rho_p x_p}{2\epsilon_0}$$

$$0 < x < x_p : E = -\frac{\rho_p}{\epsilon_0} \left(x - \frac{x_p}{2} \right) + \frac{\rho_n x_n}{2\epsilon_0}$$

PN结电场强度分布



1-29

$$E = \left(\frac{\sigma_e}{\epsilon_0} - \frac{1}{\epsilon_0} \int_0^R dr \int_0^{2\pi} d\theta r \sigma_e \right) \cdot \frac{x}{|x|}$$

$$= \frac{\sigma_e}{\epsilon_0} (1 - \pi R^2) \cdot \frac{x}{|x|}$$

